

View Online at <https://aerobasegroup.com/nsn/5961-01-470-6985>

Inclosure Material:

Ceramic

Overall Length:

0.770 inches

Overall Height:

0.175 inches

Overall Width:

0.310 inches

End Application:

E/i fscm aircraft, b-2 bomber (atb)

Component Name And Quantity:

4 transistor

Mounting Method:

Terminal

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

100.0 drain to source voltage all transistor and 100.0 drain to gate voltage all transistor and 20.0 gate to source voltage all transistor

Current Rating Per Characteristic:

0.95 amperes source cutoff current of standard range all transistor

Power Rating Per Characteristic:

1.4 watts small-signal input power, common-collector absolute all transistor

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Hardness critical process

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

07690-632049 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

14 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0